

Features:

- RoHS Compliant
- 150 Watts
- DC 4.0 GHz
- AIN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested
- Small Size

Description:

The C150N50Z4 is high performance Aluminum Nitride (AIN) surface mount termination intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating high power 90 degree couplers and for use in microstrip circuits. The termination is also RoHS compliant!

General Specifications:

Resistive Element	Thick film
Substrate	AIN Ceramic
Terminal Finish	Matte Tin over Nickel Barrier
Operating Temperature	-50 to +200°C (see de rating chart)

Electrical Specifications:

 Resistance Value:
 50 Ohms, ± 2%

 Power:
 150 Watts

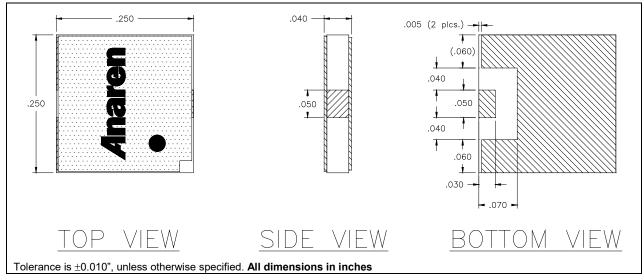
 Frequency Range:
 DC − 4.0 GHz

 Return Loss
 >24 dB DC - 2.7 GHz

 >20 dB DC - 4.0 GHz

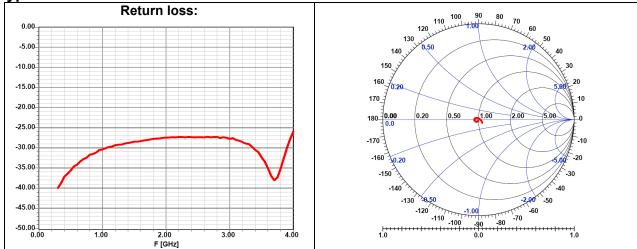
Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

Outline Drawing:

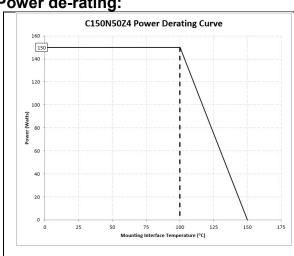




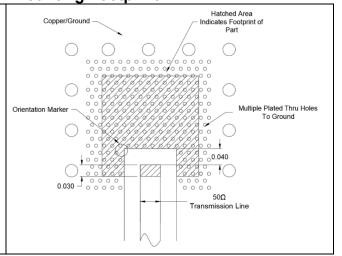
Typical Performance:



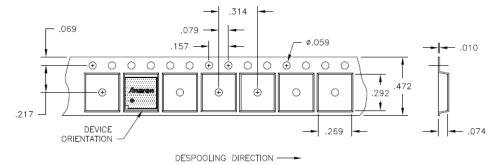
Power de-rating:



Mounting Footprint:



Tape & Reel:



Contact us:

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